Crystal Oscillator (SPXO)

- · Package size (2.5 mm × 2.0 mm × 0.74 mm)
- · Fundamental mode SPXO
- · Output: LVDS
- · Reference weight Typ.12 mg

[1] Product Number / Product Name / Marking

(1-1) Product Number / Ordering Code

X1G0059410007xx

Last 2 digits code(xx) defines Quantity.

The standard is "15", 2 000 pcs/Reel.

(1-2) Product Name / Model Name

SG2520VHN 156.250000MHz ECGSZA

[2] Operating Range

1 - 1 operating mange						
Parameter	Symbol		Specification	S	Unit	Conditions
Farameter	Symbol	Min.	Тур.	Max.	Offic	Conditions
Supply voltage	V_{CC}	1.71	1.8	1.89	V	-
	GND	0	-	0	V	-
Input voltage	V_{IN}	0	-	V_{CC}	V	-
Operating temperature range	T_use	-40	-	+85	°C	-
LVDS load condition	L_LVDS	-	100	-	Ω	Connected between OUT and OUT

[3] Frequency Characteristics

(Unless stated otherwise [2] Operating Range)

Parameter	Symbol	,	Specifications	S	Unit	Conditions	
Farameter	Symbol	Min.	Тур.	Max.	Offic	Conditions	
Output frequency	fo	=	156.250000	ē	MHz	-	
Frequency tolerance *1	f_tol	-20	-	+20	×10 ⁻⁶	T_use	

^{*1} Frequency tolerance includes Initial frequency tolerance, Frequency / temperature characteristics, Frequency / voltage coefficient and aging (10 years, +25 °C).

[4] Electrical Characteristics

(Unless stated otherwise [2] Operating Range)

[4] Electrical Character	(UI	iless stated	otherwise [2] Operating hange)			
Parameter	Symbol		Specification	าร	Unit	Conditions
i ai ai lietei	Symbol	Min.	Тур.	Max.	Offic	Conditions
Start-up time	t_str	-	=	10	ms	t = 0 at 90 % Vcc
Current consumption	I _{cc}	-	=	25	mA	
Stand-by current	l_std	-	-	30	μA	ST = GND
	V _{OD}	0.25	-	0.45	V	Differential output voltage, V _{OD1} , V _{OD2}
Output voltage	dV_{OD}	-	-	50	mV	$dV_{OD} = V_{OD1} - V_{OD2} $
Output voltage	Vos	0.65	-	0.85	V	Offset voltage
	dV _{OS}	-	-	50	mV	$dV_{OS} = V_{OS1} - V_{OS2} $
Differential swing	V_{SW}	0.5		0.9	V	Differential output peak to peak voltage
Rise time	tr	-	-	0.35	ns	20 % to 80 % of differential swing
Fall time	tf	-	-	0.35	ns	80 % to 20 % of differential swing
Symmetry	SYM	45	50	55	%	At output crossing point
Innut valtage	V_{IH}	70 % Vcc	-	-	V	ST terminal
Input voltage	V_{IL}	-	-	30 % Vcc	V	ST terminal
Output disable time (ST)	tstp_st	-	-	100	ns	ST terminal HIGH → LOW
Output enable time (ST)	tsta_st	-	-	10	ms	ST terminal LOW → HIGH
Phase jitter	t _{PJ}	-	-	70	fs	Offset freq.: 12 kHz to 20 MHz

[For other general specifications, please refer to the attached Full Data Sheet below]

Low Phase Jitter Crystal Oscillator: SG2016VHN/SG2520VHN

Features

Crystal oscillator (SPXO)

Frequency range (fo): 25 MHz to 500 MHz

Output: LVDS

1.8 V Typ. / 2.5 V Typ. / 3.3 V Typ. Supply voltage:

Operating temperature: -40 °C to +105 °C

Frequency tolerance: $\pm 20 \times 10^{-6}$

38 fs Typ. (fo = 156.25 MHz) Low phase jitter:

SG2016VHN SG2520VHN 2.0 × 1.6 mm $2.5 \times 2.0 \text{ mm}$

Applications

- Network equipment (Router, Switch, Optical module, etc.)
- Data center
- Test and Measurement Equipment, Factory Automation

 2.0 ± 0.1

#1

High Speed Converters like ADC and DAC

Description

5G will increase network communication traffic exponentially. A 5G communication network requires high-speed and wide bandwidth, while keeping the noise level to a minimum. This can be achieved with a high frequency, low jitter reference clock for the communication equipment. Optical communication modules for 400 Gbps / 800 Gbps transmission over 80 km require a small form factor, ±20 x 10⁻⁶ stability reference clock. The SG2016VHN/SG2520VHN is the next generation to the very popular SG3225VEN family offering the same combination of features with a wide range of available frequencies, low jitter, and improved frequency tolerance performance due to using an in-house designed IC with temperature compensation in a 63% smaller package.

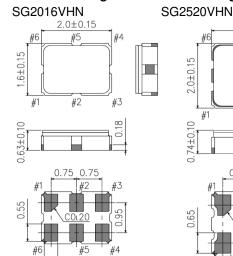
2.5±0.15

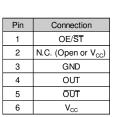
#2

0.47 #5

#3

Outline Drawing and Terminal Assignment

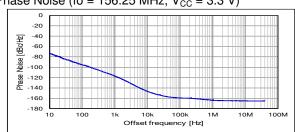




0.40

Typical Performance

Phase Noise (fo = 156.25 MHz, V_{CC} = 3.3 V)



Phase Jitter (12 kHz to 20 MHz): 38 fs Typ.

[1] Product Number / Product Name

(1-1) Product Number

SG2016VHN: X1G006121xxxx15 SG2520VHN: X1G005941xxxx15

(Please contact Epson for details)

(1-2) Product Name (Standard Form)

1)Model

2Output (V: LVDS)

③Frequency

4 Supply voltage

⑤Frequency tolerance (C: ±20 × 10⁻⁶)

©Operating temperature

7Function

Output disable status

(Z: High impedance)

Output option

 4Sι	upply voltage
Ε	1.8 V Typ.
D	2.5 V Typ.
С	3.3 V Typ.

6 0	perating temperature
G	-40 °C to +85 °C
Н	-40 °C to +105 °C

⑦Fι	ınction
Р	Output Enable
S	Standby
_	- to

	V _{SW} = 500 mV to 900 mV						
	V _{SW} = 800 mV to 1 600 mV						
С	$V_{SW} = 600 \text{ mV to } 1 200 \text{ mV}$						

^{*}Not available for $V_{CC} = 1.8 \text{ V Typ.}$

[2] Absolute Maximum Ratings

Parameter	Symbol		Specification		Unit	Conditions
Farameter		Min.	Тур.	Max.		
Maximum supply voltage	V _{CC}	-0.3	-	4.0	V	
Input voltage	Vin	-0.3	-	$V_{CC} + 0.5$	V	OE/ST terminal
Storage temperature range	T_stg	-55	-	+125	°C	

[3] Operating Range

Parameter	Symbol		Specification		Unit	Conditions
Farameter	Symbol	Min.	Тур.	Max.	Offic	Conditions
		1.71	1.8	1.89	V	Suffix: E, Output option: A or C
Supply voltage	V _{CC}	2.375	2.5	2.625	V	Suffix: D
		3.135	3.3	3.465	V	Suffix: C
Supply voltage	GND	0.0	0.0	0.0	V	
Operating temperature range	T 1100	-40	+25	+85	°C	Suffix: G
	T_use	-40	+25	+105	°C	Suffix: H
LVDS load condition	L_LVDS		100		Ω	

^{*} Power supply startup time (0 %V_{CC} \rightarrow 90 %V_{CC}) should be more than 150 μ s

[4] Frequency Characteristics

(Unless stated otherwise [3] Operating Range)

Parameter	Symbol				Unit	Conditions
Farameter	Syllibol	Min.	Тур.	Max.	Offit	Conditions
Output frequency *1	fo	25	-	500	MHz	
Frequency tolerance *2	f_tol	-20	-	+20	×10 ⁻⁶	Suffix: C

^{*1} Please contact Epson for available frequencies

 $^{^{\}star}$ A 0.1 μF and a 10 μF bypass capacitor should be connected between V_{CC} and GND pins located close to the device

^{*2} Frequency tolerance includes Initial frequency tolerance, Frequency / temperature characteristics, Frequency / voltage coefficient and aging (10 years, +25 °C).

^{*}Aging is estimated from environmental reliability tests; expected amount of the frequency variation. This does not intend to guarantee the product-life cycle.

Damanatan	ı	1.1	0 100			
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Startup time	t_str	-	-	10	ms	t = 0 at 90 % V _{CC}
		-	-	25	mA	Output option: A, fo $<$ 212 MHz $V_{CC} = 2.5 V, 3.3 V Typ.$
		-	-	28	mA	Output option: A, fo \ge 212 MHz V_{CC} = 2.5 V, 3.3 V Typ.
		-	-	30	mA	Output option: B, fo < 212 MHz V_{CC} = 2.5 V, 3.3 V Typ.
		-	-	35	mA	Output option: B, fo \ge 212 MHz V_{CC} = 2.5 V, 3.3 V Typ.
Current consumption	I _{cc}	-	-	25	mA	Output option: C, fo < 212 MHz V _{CC} = 2.5 V, 3.3 V Typ.
		-	-	28	mA	Output option: C, 212 MHz \leq fo $<$ 392 MHz V_{CC} = 2.5 V, 3.3 V Typ.
		-	-	30	mA	Output option: C, fo \geq 392 MHz V_{CC} = 2.5 V, 3.3 V Typ.
		-	-	25	mA	Output option: A or C $V_{CC} = 1.8 \text{ V Typ.}$
Disable current	l_dis	-	-	20	mA	OE = GND
Stand-by current	I std	-	-	30	μA	ST = GND, T_use Max. = +85 °
•		-	-	60	μA	ST = GND, T_use Max. = +105
Rise time / Fall time	tr / tf	-	-	0.35	ns	20 % - 80 % of V _{SW}
Symmetry	SYM	45	50	55	%	At output crossing point
	V _{OD}	250	-	450	mV	Output option: A
		400	-	800	mV	Output option: B Not available for $V_{CC} = 1.8 \text{ V Typ.}$
Output voltage		300	-	600	mV	Output option: C
Cutput Voltage	dV_{OD}	-	-	50	mV	V _{OD1} - V _{OD2}
	V _{OS}	1.15	-	1.35	V	V _{CC} = 2.5 V, 3.3 V Typ.
		0.65	-	0.85	V	V _{CC} = 1.8 V Typ.
	dV _{OS}	-	-	50	mV	V _{OS1} - V _{OS2}
		500	-	900	mV	Output option: A
Differential swing	V_{SW}	800	-	1 600	mV	Output option: B Not available for V _{CC} = 1.8 V Typ.
		600	-	1 200	mV	Output option: C
Input voltage	V _{IH}	70 % V _{CC}	-	-	V	—OE/ST terminal
	V _{IL}	-	-	30 % V _{CC}	V	11 11 11 11 15
Output disable time (OE)	tstp_oe	-	-	100	ns	Measured from the time OE pir crosses 30 % V _{CC}
Output disable time (ST)	tstp_st	-	-	100	ns	Measured from the time \overline{ST} pin crosses 30 % V _{CC}
Output enable time (OE)	tsta_oe	-	-	500	ns	Measured from the time OE pir crosses 70 % V _{CC}
Output enable time (ST)	tsta_st	-	-	10	ms	Measured from the time \overline{ST} pin crosses 70 % V_{CC}
Phase jitter		-	-	250	fs	fo < 100 MHz
V _{CC} = 2.5 V, 3.3 V Typ. Offset frequency		-	-	100	fs	100 MHz ≤ fo ≤ 156 MHz
fo < 50 MHz; 12 kHz to 5 MHz		-	-	60	fs	156 MHz < fo ≤ 212 MHz
fo ≥ 50 MHz: 12 kHz to 20 MHz	t _{PJ}	-	-	50	fs	fo > 212 MHz
Phase jitter	493	-	-	400	fs	fo < 100 MHz
V _{CC} = 1.8 V Typ.		-	-	130	fs	100 MHz ≤ fo ≤ 156 MHz
Offset frequency fo < 50 MHz: 12 kHz to 5 MHz		-	-	70	fs	156 MHz < fo ≤ 212 MHz
fo ≥ 50 MHz: 12 kHz to 20 MHz		-	-	60	fs	fo > 212 MHz

[6] Thermal resistance (For reference only)

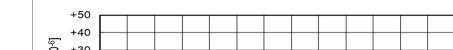
Parameter	Symbol	Specification			Unit	Conditions
Farameter	Symbol	Min.	Тур.	Max.	Offic	Conditions
Junction temperature	Tj	-	-	140	°C	
Junction to case	θјс	-	114	-	°C/W	SG2016VHN
	Ojc	-	122	-	°C/W	SG2520VHN
Junction to ambient	Aia	-	243	-	°C/W	SG2016VHN
	θја	-	155	-	°C/W	SG2520VHN

[7] Typical Performance Characteristics (For reference only)

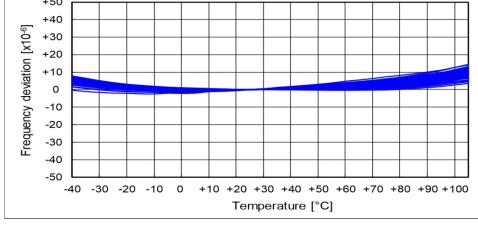
The following data shows typical performance characteristics

fo = 156.25 MHz, -40 °C to +105 °C, reference at +25 °C

(7-1) Frequency / Temperature Characteristics

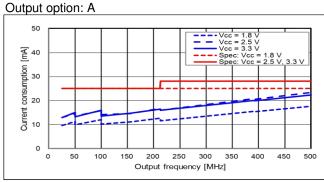


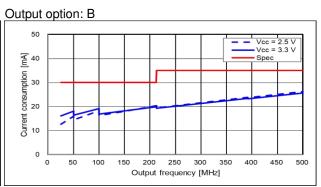
n = 50 pcs

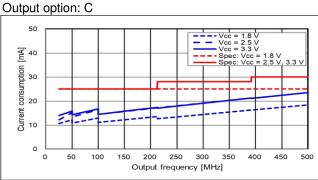


(7-2) Current Consumption

T_use = +25 °C, Frequency Dependency



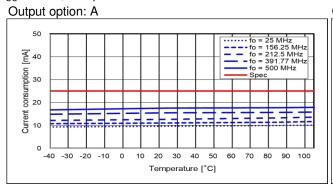


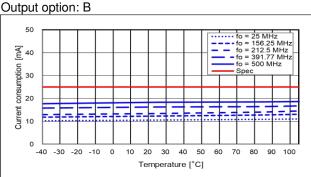


Spec No: SGxxxxVHN_E_Ver1.01

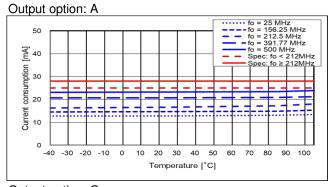
(7-2) Current Consumption [cont'd]

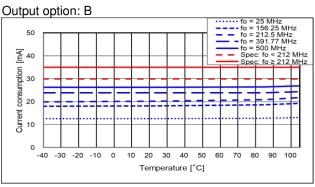
V_{CC} = 1.8 V, Temperature Characteristic

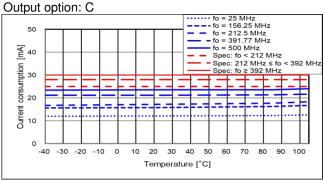




 $V_{CC} = 2.5 \text{ V}$, Temperature Characteristic



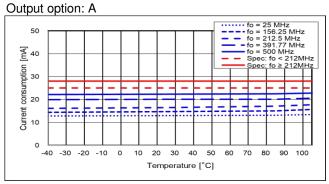


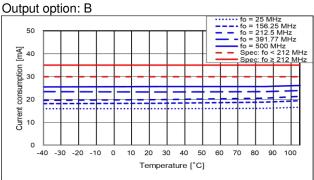


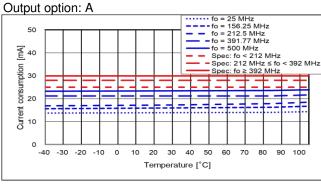
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(7-2) Current Consumption [cont'd]

V_{CC} = 3.3 V, Temperature Characteristic

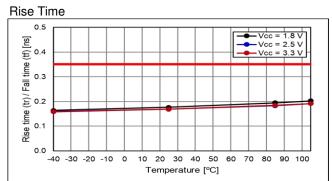


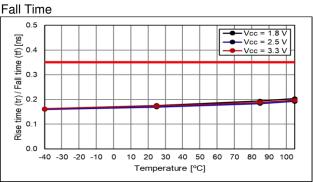




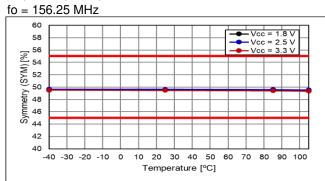
(7-3) Rise Time / Fall Time Temperature Characteristic

fo = 156.25 MHz

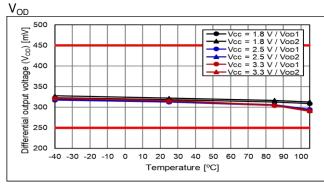


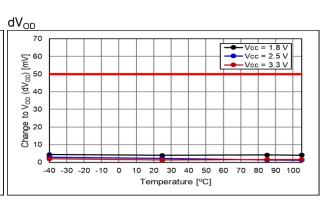


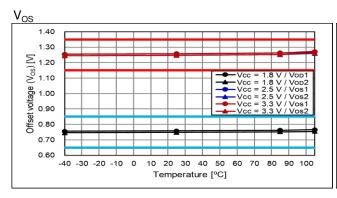
(7-4) Symmetry Temperature Characteristic

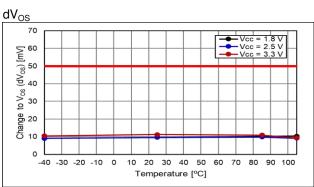


(7-5) Output Voltage Temperature Characteristic

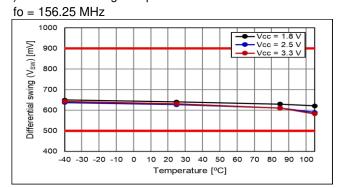




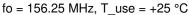


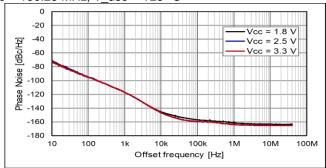


(7-6) Differential Swing Temperature Characteristic



(7-7) Phase Noise and Phase Jitter



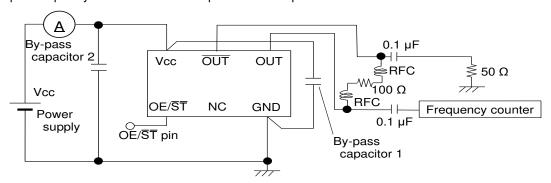


V_{CC}	Phase Jitter*
1.8 V	47 fs
2.5 V	38 fs
3.3 V	38 fs

^{*} Offset frequency: 12 kHz to 20 MHz

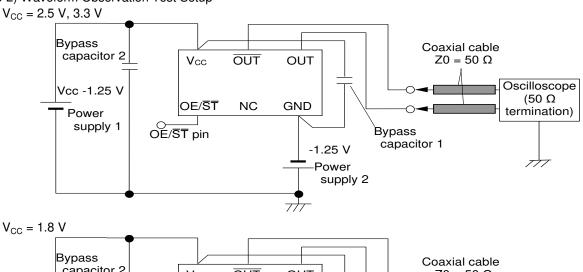
[8] Test Circuit

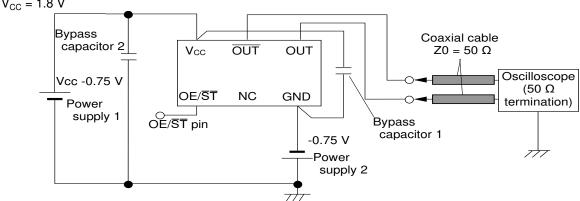
(8-1) Output Frequency and Current Consumption Test Setup



^{*} To measure Disable current or Stand-by current, OE/ST terminal is connected to GND

(8-2) Waveform Observation Test Setup





^{*} Each output trace should be same length

(8-3) Conditions

(1) Oscilloscope

The bandwidth should be a minimum of 5 times the measurement frequency

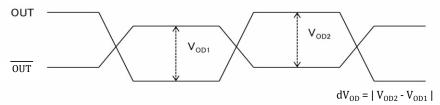
- (2) A 0.1 μF and a 10 μF bypass capacitor should be connected between V_{CC} and GND pins located close to the device
- (3) Use a current meter with a low internal impedance
- (4) Power Supply

Power supply startup time (0 % $V_{CC}{\to}90$ % $V_{CC})$ should be more than 150 μs Power supply impedance should be as low as possible

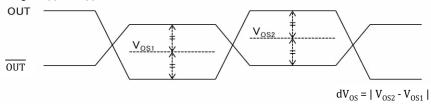
(8-4) Timing Chart

(1) Output Waveform and Level

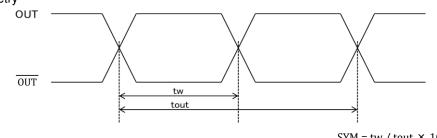
Output voltage V_{OD} / dV_{OD}



Output voltage V_{OS} / dV_{OS}

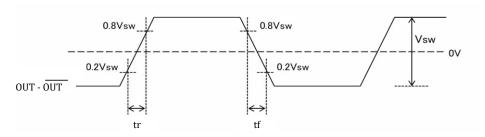


Symmetry

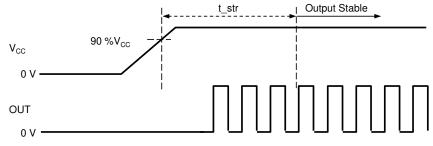


SYM = tw / tout \times 100 [%]

Rise Time / Fall Time



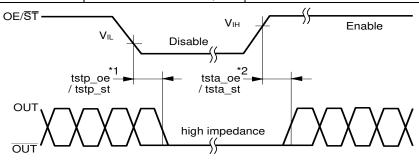
(2) Output Frequency Timing



(8-4) Timing Chart [cont'd]

(3) $OE/\overline{S}\overline{T}$ Function and Timing

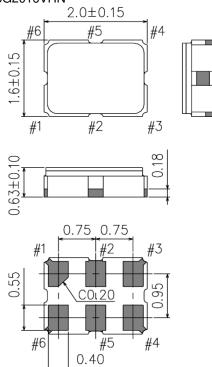
OE/ST Terminal	Osc. Circuit	Output status	
"H" or OPEN	Oscillation	Specified frequency is output: Enable	
"L"	OE: Oscillation	Output becomes high impedance: Disable	
	ST: Oscillation stop		

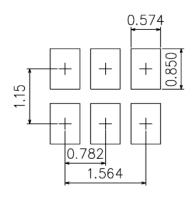


- *1 The period from $OE/\overline{ST} = V_{IL}$ to OUT = High impedance (Disable)
- *2 The period from $OE/\overline{ST} = V_{IH}$ to OUT = Enable
- * OE/ST terminal voltage level should not exceed supply voltage when using OE/ST function.

 Please note that OE/ST rise time should not exceed supply voltage rise time at the start-up.

[9] Outline Drawing and Recommended Footprint (9-1) SG2016VHN





For stable operation, it is recommended that 0.1 μF and 10 μF bypass capacitors should be connected between V_{CC} and GND and placed

as close to the $\ensuremath{V_{\text{CC}}}$ pin as possible.

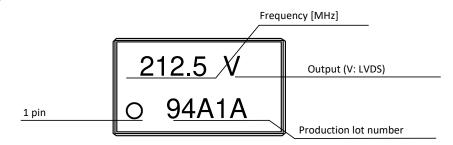
Terminal coating: Au plating

Reference Weight Typ.: 7.6 mg

Terminal Assignment

Pin#	Connection	Function			
		OE/ST terminal / active high			
			OE/ST Terminal	Osc. Circuit	Output status
#1 OE/ST		"H" or OPEN	Oscillation	Specified frequency is output: Enable	
		" ₁ "		OE: Oscillation	Output becomes high impedance: Disable
			ST: Oscillation stop	Output becomes high impedance. Disable	
#2	NC	_	-		
#3	GND	GND terr	GND terminal		
#4	OUT	Output terminal (Positive)			
#5	ŌŪŦ	Output terminal (Negative)			
#6	V _{CC}	V _{CC} terminal			

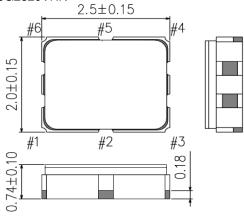
Marking

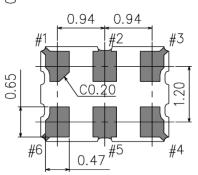


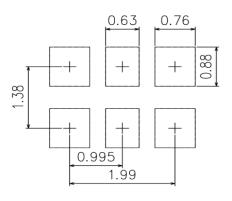
Units: mm

Units: mm

(9-2) SG2520VHN







For stable operation, it is recommended that 0.1 μ F and 10 μ F bypass capacitors should be connected between V_{CC} and GND and placed as close to the V_{CC} pin as possible.

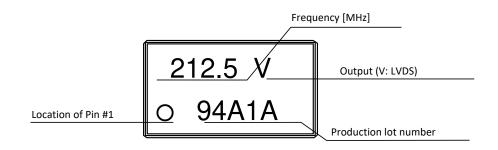
Terminal coating: Au plating

Reference Weight Typ.: 11.8 mg

Terminal Assignment

Pin#	Connection	Function			
		OE/ST terminal / active high			
			OE/ST Terminal	Osc. Circuit	Output status
#1 OE/ST		"H" or OPEN	Oscillation	Specified frequency is output: Enable	
		" ₁ "		OE: Oscillation	Output becomes high impedance: Disable
			ST: Oscillation stop	Output becomes high impedance. Disable	
#2	NC	_	-		
#3	GND	GND terr	GND terminal		
#4	OUT	Output terminal (Positive)			
#5	ŌŪŦ	Output terminal (Negative)			
#6	V _{CC}	V _{CC} terminal			

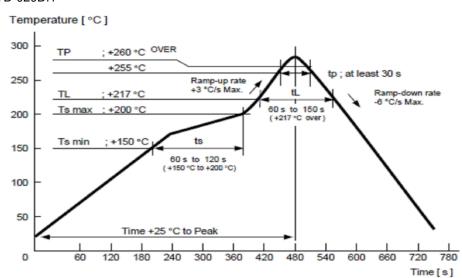
Marking



[10] Moisture Sensitivity Level

Parameter	Specification	Conditions
MSL	LEVEL 1	IPC/JEDEC J-STD-020D.1

[11] Reflow Profile IPC/JEDEC J-STD-020D.1



[12] Packing Information

(12-1) SG2016VHN

(1) Packing Quantity

The last two digits of the Product Number (X1G006121xxxxxxx) are a code that defines the packing quantity. The standard is "15" for a 2 000 pcs/Reel.

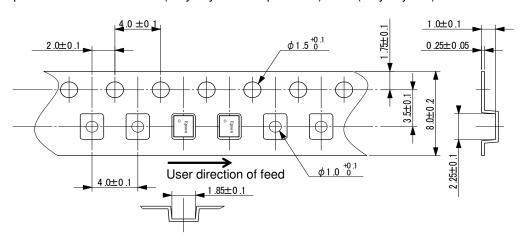
(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

1) Tape Dimensions

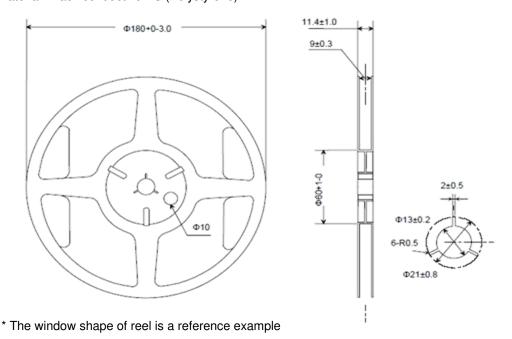
Carrier Tape Material: Black conductive PS (Polystyrene)

Top Tape Material: Antistatic PET (Polyethylene Terephthalate) + PE (Polyethylene)



2) Reel Dimensions

Reel Material: Black conductive PS (Polystyrene)



3) Storage Environment

We recommend to keep at normal temperature and normal humidity in a packed condition.

Units: mm

Units: mm

(12-2) SG2520VHN

(1) Packing Quantity

The last two digits of the Product Number (X1G005941xxxxxxx) are a code that defines the packing quantity. The standard is "15" for a 2 000 pcs/Reel.

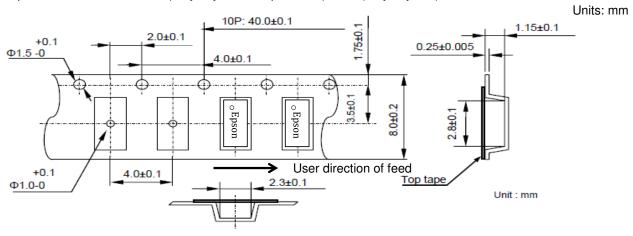
(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

1) Tape Dimensions

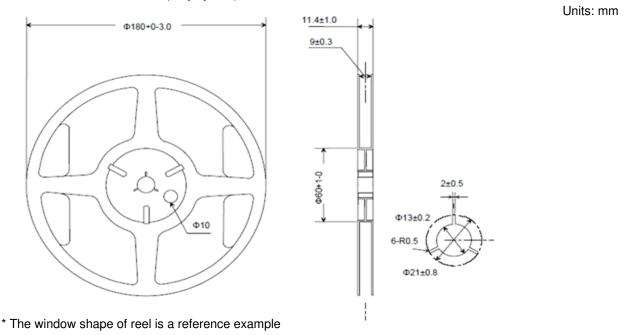
Carrier Tape Material: Black conductive PS (Polystyrene)

Top Tape Material: Antistatic PET (Polyethylene Terephthalate) + PE (Polyethylene)



2) Reel Dimensions

Reel Material: Black conductive PS (Polystyrene)



3) Storage Environment

We recommend to keep at normal temperature and normal humidity in a packed condition.

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[13] Handling Precautions

Prior to using this product, please carefully read the section entitled "Precautions" on our Web site (https://www5.epsondevice.com/en/information/#precaution) for instructions on how to handle and use the product properly to ensure optimal performance of the product in your equipment. Before using the product under any conditions other than those specified therein,

please consult with us to verify and confirm that the performance of the product will not be negatively

affected by use under such conditions.

In addition to the foregoing precautions, in order to avoid the deteriorating performance of the produc

In addition to the foregoing precautions, in order to avoid the deteriorating performance of the product, we strongly recommend that you DO NOT use the product under ANY of the following conditions:

- (1) Do not expose this product to excessive mechanical shock or vibration.
- (2) This product can be damaged by mechanical shock during the soldering process depending on the equipment used, process conditions, and any impact forces experienced. Always follow appropriate procedures, particularly when changing the assembly process in any way and be sure to follow applicable process qualification standards before starting production.
- (3) These devices are sensitive to ESD, use appropriate precautions during handling, assembly, test, shipment, and installation.
- (4) The use of ultrasonic technology for cleaning, bonding, etc. can damage the Xtal unit inside this product. Please carefully check for this consideration before using ultrasonic equipment for volume production with this product.
- (5) Noise and ripple on the power supply may have undesirable affects on operation and cause degradation of phase noise characteristics. Evaluate the operation of this device with appropriate power supplies carefully before use.
- (6) When applying power, ensure that the supply voltage increases monotonically for proper operation.
 On power down, do not reapply power until the supplies, bypass capacitors, and any bulk capacitors are completely discharged since that may cause the unit to malfunction.
- (7) Aging specifications are estimated from environmental reliability tests and expected frequency variation over time. They do not provide a guarantee of aging over the product lifecycle.
- (8) The metal cap on top of the device is directly connected to the GND terminal (pin #2). Take necessary precautions to prevent any conductor not at ground potential from contacting the cap as that could cause a short circuit to GND.
- (9) Do not route any signal lines, supply voltage lines, or GND lines underneath the area where the oscillators are mounted including any internal layers and on the opposite side of the PCB. To avoid any issues due to interference of other signal lines, please take care not to place signal lines near the product as this may have an adverse affect on the performance of the product.
- (10) A bypass capacitor of the recommended value(s) must be connected between the V_{CC} and GND terminals of the product. Whenever possible, mount the capacitor(s) on the same side of the PCB and as close to the product as possible to keep the routing traces short.
- (11) Power supply connections to V_{CC} and GND pins should be routed as thick as possible while keeping the high frequency impedance low in order to get the best performance.
- (12) The use of a filter or similar element in series with the power supply connections to protect from electromagnetic radiation noise may increase the high frequency impedance of the power supply line and may cause the oscillator to not operate properly. Please verify the design to ensure sufficient operational margin prior to use.
- (13) Keep PCB routing from the output terminal(s) to the load as short as possible for best performance.
- (14) The Enable (OE or ST) input terminal is high impedance and so susceptible to noise. Connect it to a low impedance source when used and when not used it is recommended to connect it to Vcc for active high inputs and GND for active low inputs.
- (15) Do not short the output to GND as that will damage the product. Always use with an appropriate load resistor connected.
- (16) This product should be reflowed no more than 3 times. If rework is needed after reflow, please correct it with a soldering iron with the tip set for a temperature of +350 °C or less and only contact each terminal once and for no more than 5 seconds. If this product is mounted on the bottom of the board during a reflow please check that it soldered down properly afterwards.

[A۱	[Availability of mounting conditions]					
	Reflow on the board	Avallable				
	Reflow under the board	The parts may fall. Please judge whether it is possible to implement.				
	Soldering pot/bath (Dip soldering system, Flow soldering system)	Not Avallable				
	Soldering iron	Avallable				

- (17) Product failures during the warranty period only apply when the product is used according to the recommended operating conditions described in the specifications. Products that have been opened for analysis or damaged will not be covered. It is recommended to store and use in normal temperature and humidity environments described in the specifications to ensure frequency accuracy and prevent moisture condensation. If the product is stored for more than one year, please confirm the pin solderability prior to use.
- (18) If the oscillation circuit is exposed to condensation, the frequency may change or oscillation may stop. Do not use in any conditions where condensation occurs.
- (19) Do not store or use the product in an environment where it can be exposed to chemical substances that are corrosive to metal or plastics such as salt water, organic solvents, chemical gasses, etc. Do not use the product when it is exposed to sunlight, dust, corrosive gasses, or other materials for long periods of time.
- (20) When using water-soluble solder flux make sure to completely remove the flux residue after soldering.

 Pay particular attention when the residues contain active halogens which will negatively affect the product and its performance.
- (21) Terminals on the side of the product are internally connected to the IC, be careful not to cause short-circuits or reduce the insulation resistance of them in any way.
- (22) Should any customer use the product in any manner contrary to the precautions and/or advice herein, such use shall be done at the customer's own risk.

PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification. ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.

WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs, Seiko Epson made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired IATF 16949 certification that is requested strongly by major manufacturers as standard.

IATF 16949 is the international standard that added the sector-specific supplemental requirements for automotive industry based on ISO9001.

■ Explanation of marks used in this datasheet



●Pb free.



Complies with EU RoHS directive.

*About the products without the Pb-free mark.

Contains Pb in products exempted by EU RoHS directive

(Contains Pb in sealing glass, high melting temperature type solder or other)

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